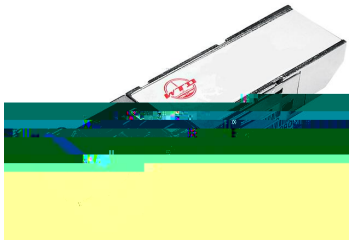

	1	Icc	mA	-	300
			mV	150	1100
			mV	300 -	600
TX_fault /LOS	(TTL)	VOH	V	2.0 -	Vcc
		VOL	V	0 -	0.8
TX_disable	(TTL)	VOH	V	2.0 -	Vcc
		VOL	V	0 -	0.8
		Po	dBm	-9.5	-3
		λc	nm	830	860
		EX	dB	9	
(RMS)		Δλ	nm		4
	2	TJ	UI		0.284
	3	RIN	dB/Hz		-120
		GE			
/		Trise/Tfall	ps		260
		-	dB		1
		Poff	dBm		-45
		λc	nm	770	870
	4	S	dBm		-18
		Pin	dBm	0	
			dBm		-18
				-35	

		dB	0.5		5

Note1.

Note2. 1.25Gbps 7 .

Note3. RIN 12dB

Note4. PRBS 2^7-1 1.25Gb/s EX=10dB BER<10^{-12}

RTXM191-552	SFP	1.25G	850nm FP	-9.5~ -3dBm	PIN	< -18dBm	-40~85°C	0.55km	DDM, RoHS